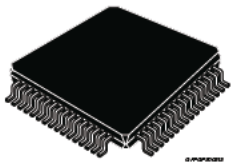
TDA7786C

ELITE tuner for AM/FM car-radio

Datasheet - production data



LQFP64

Features

- FM and AM reception
- Fully integrated VCO for world tuning
- Integrated AM LNA and PIN diodes
- Automatic self alignment for FM front-end pre-selection filter and image rejection
- Integrated IF filters with high selectivity, dynamic range and adaptive bandwidth control
- Drift-free Digital-IF signal processing with high performance
- High performance stereo decoder with noise-blanker
- I^2C bus-controlled
- Single 5 V supply
- LQFP64 package

Description

The TDA7786C (ELITE) tuner is an AM/FM tuner IC for car-radio applications.

It integrates mixers and IF amplifiers for AM and FM fully integrated VCO and PLL synthesizer, IF-processing including adaptive bandwidth control, stereo decoder.

The utilization of digital signal processing results in numerous advantages: very low number of external components, very small space occupation and easy application, very high selectivity due to digital filters, high customization possibility through software control, automatic alignment and a powerful DSP for advanced processing.

Table 1. Device summary

Order code	Package	Packing
TDA7786C	LQFP64 (10x10x1.4mm)	Tray
TDA7786CTR	LQFP64 (10x10x1.4mm)	Tape & Reel

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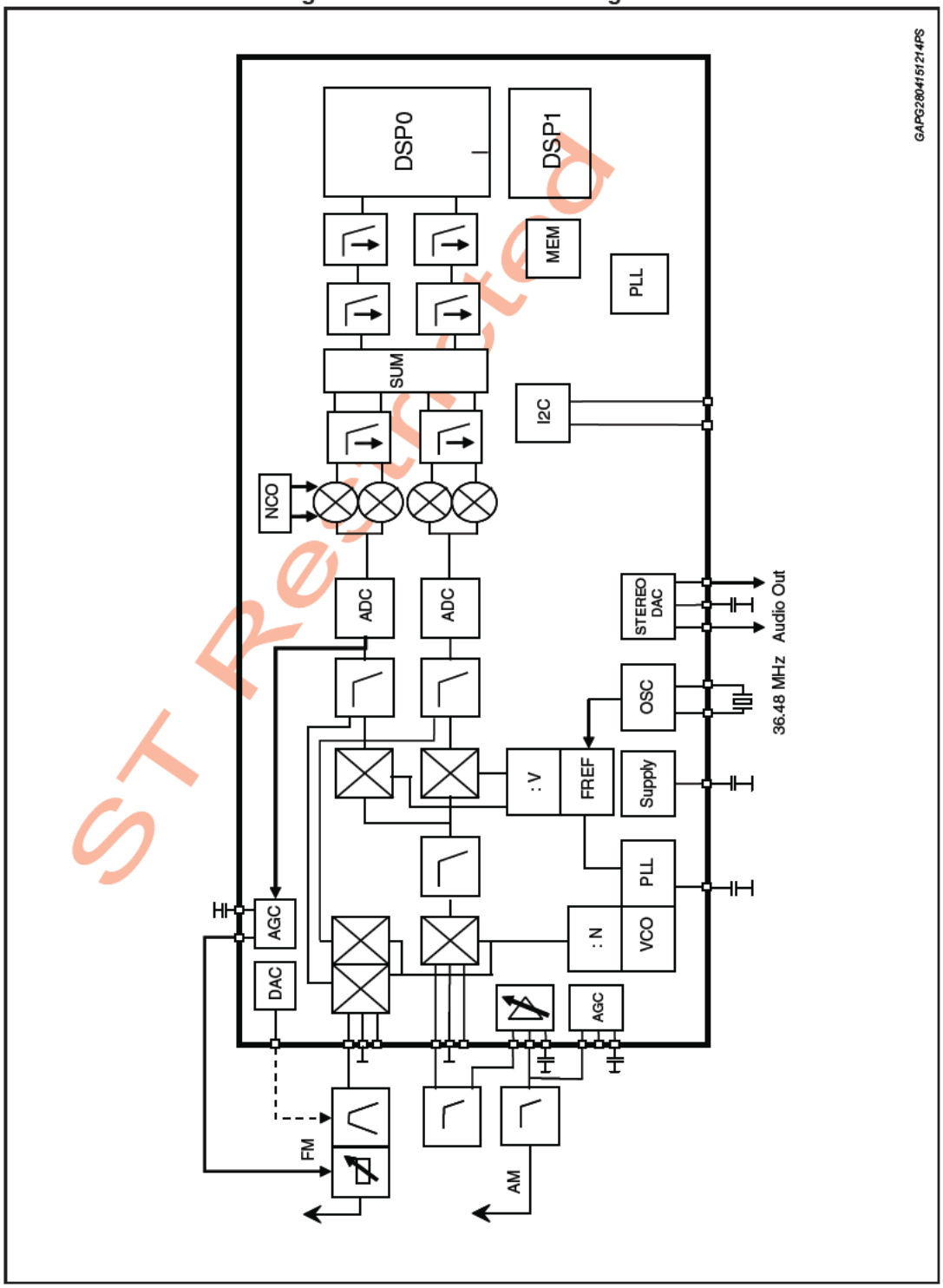
1.1 Block diagram

Figure 1. Functional block diagram



1.2 Pin description

Figure 2. Pin connection (top view)

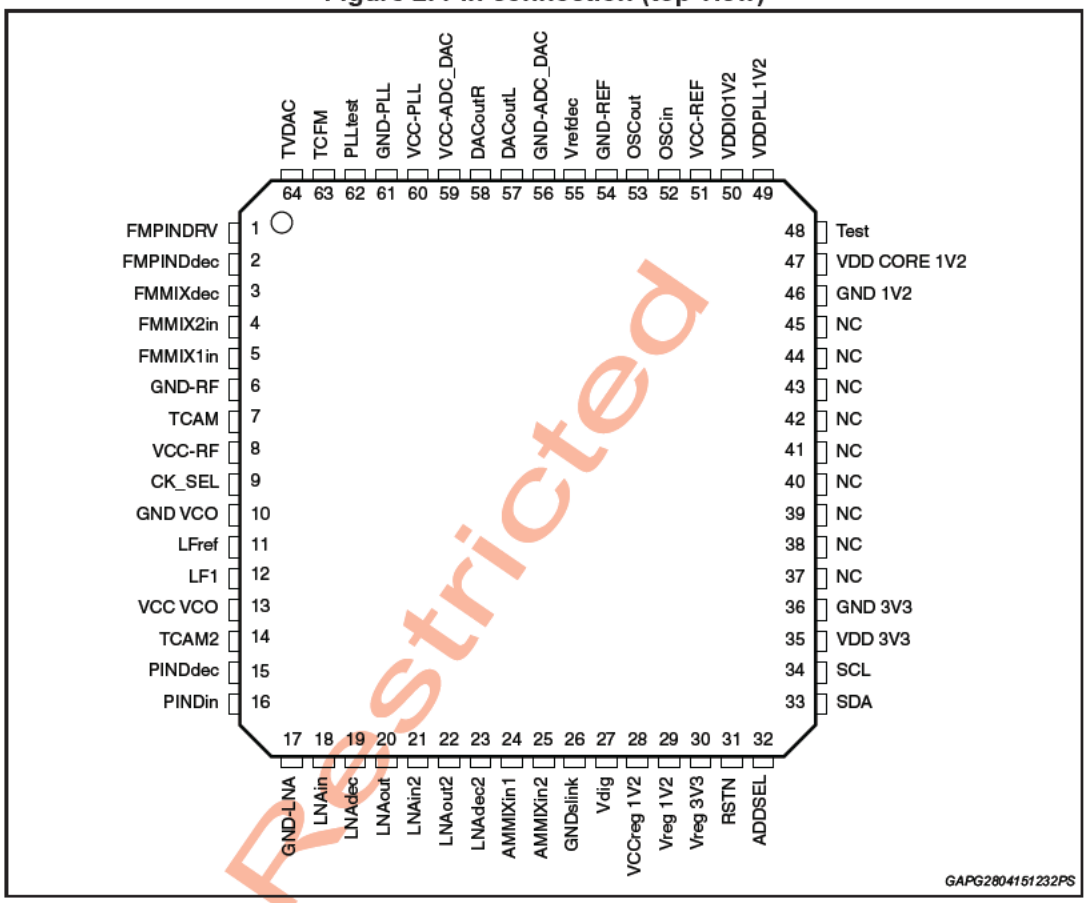


Table 2. Pin description

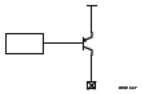
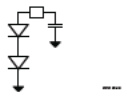
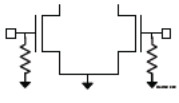
Pin	Pin name	I/O	Function	Description	Equivalent circuit
1	FMPINDRV	Out	FM	FM PIN diode driver output	
2	FMPINDdec	In		Integrated FM PINdiode decoupling	
3	FMMIXdec	-		FM RF signal ground	
4	FMMIXin2	In		FM mixer input 2	
5	FMMIXin1	In		FM mixer input 1	
6	GNDRF	-	-	RF power ground	-

Table 2. Pin description (continued)

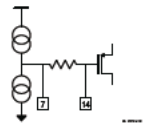
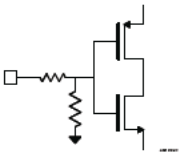
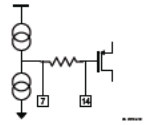
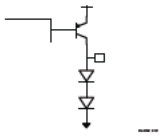
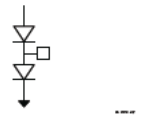
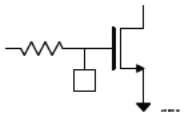
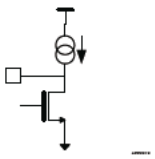
Pin	Pin name	I/O	Function	Description	Equivalent circuit
7	TCAM	-	-	AM AGC time constant	
8	VCCRF	In	-	RF 5 V supply	-
9	CK_SEL	In	-	Master/Slave clock operation select	
10	GNDVCO	-	VCO	VCO ground	-
11	LFref	-		Loop filter reference	-
12	LF1	-		Loop filter output	-
13	VCCVCO	In		VCO 5V supply	-
14	TCAM2	-		AM AGC 2nd order time constant	
15	PINDdec	-	AM pin diode	AM AGC internal PIN diode decoupling	
16	PINDin	-		AM AGC internal PIN diode input	
17	GNDLNA	-	AM LNA	AM LNA ground	-
18	LNAin	In		AM LNA input	
19	LNAdec	-		AM LNA decoupling	
20	LNAout	Out		AM LNA output	-
21	LNAin2	-		AM LNA input 2nd stage	-

Table 2. Pin description (continued)

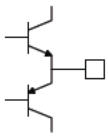
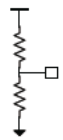
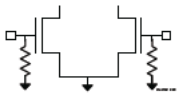
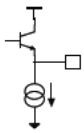
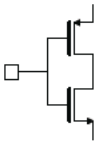
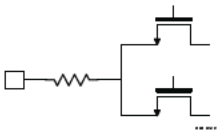
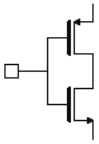
Pin	Pin name	I/O	Function	Description	Equivalent circuit
22	LNAout2	-	AM LNA	AM LNA output 2nd stage	
23	LNAdec2	-		AM LNA decoupling 2nd stage	
24	AMMIXin1	In	AM mixer inputs	AM mixer input 1	
25	AMMIXin2	In		AM mixer input 2	
26	GNDSLINK	-	Supply, ground and reset	Internal inter-IC communication bus ground	-
27	Vdig	In		Front-end digital 5 V supply	-
28	VCCreg1V2	In		Internal 1.2 V regulator 5 V supply	-
29	REG1V2	Out		Internal 1.2 V regulator output	
30	Vreg3v3	Out		Internal 3.3 V regulator output	
31	RSTN	In		Reset (low active) Pull-up 50 kΩ to 3.3 V IO supply	
32	ADDSEL	In	I2C interface	Pull-down 50 kΩ to ground	-
33	SDA	In/Out		I2C bus data Pull-up 50 kΩ to 3.3 V IO supply	
34	SCL	In		I2C bus clock Pull-up 50 kΩ to 3.3 V IO supply	
35	VDD3V3	In	-	IO ring (3.3 V) supply	-
36	GND3V3	-	-	IO ring (3.3 V) supply	-
37 to 45	NC	-	-	Not connected	-
46	GND1V2	-	-	DSP core ground	-

Table 2. Pin description (continued)

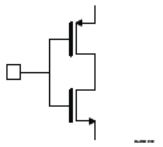
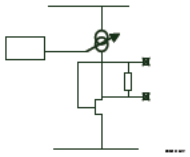
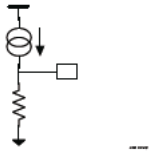
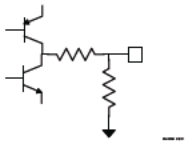
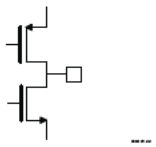
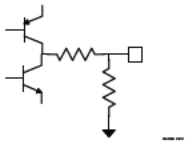
Pin	Pin name	I/O	Function	Description	Equivalent circuit
47	VDD core 1V2	In	-	DSP core 1.2 V supply	-
48	Test	In	-	Test Mode Pull-down 50 kΩ to ground	
49	VDDPLL1V2	In	-	Digital PLL 1.2 V supply	-
50	VDDIO1V2	In	-	Internal inter-IC communication 1.2 V supply	-
51	VCC-REF	In	-	Front-end reference frequency and regulator 5 V supply	-
52	OSCin	In	Oscillator	Crystal oscillator input	-
53	OSCout	Out		Crystal oscillator output	
54	GND-REF	-	-	Front-end reference frequency and regulator ground	-
55	Vrefdec	-	-	3.3 V Bias generation decoupling	
56	GND-ADC_DAC	-	DAC	IFADC and audio DAC ground	-
57	DACoutL	Out		Audio output left	
58	DACoutR	Out		Audio output right	
59	VCC-ADC_DAC	In		IFADC and audio DAC 5 V supply	-
60	VCC-PLL	In	PLL	Tuning PLL 5 V supply	-
61	GND-PLL	-		Tuning PLL ground	-
62	PLLtest	Out		PLL Test output	

Table 2. Pin description (continued)

Pin	Pin name	I/O	Function	Description	Equivalent circuit
63	TCFM	-	-	FM AGC time constant	
64	TVDAC	Out	-	Tuning voltage output	-

2 Function description

2.1 FM - mixers

The FM Image Rejection mixer has two single ended inputs, selectable through software. They are designed to achieve best performance both in case of tuned Preselection and of a fixed band-pass Preselection without tuning for lower cost applications.

The input frequency is down-converted to very low IF with high image rejection.

The tuned application is supported by an 8-bit tuning DAC. The alignment of the DAC is performed automatically on-chip.

2.2 FM - AGC

The programmable RFAGC senses the mixer input to avoid overload.

When the RFAGC threshold is reached, the PIN diode output is activated in order to attenuate the incoming RF signal.

The PIN diode driver is able to drive external PIN diodes with up to 15 mA current.

The time constant of the FM AGC is defined by the combination of an external capacitor and internal currents. There are two programmable attack and decay time constants.

2.3 AM - LNA

The integrated AM LNA feature is integrated with low-noise and high IIP2 and IIP3. The gain of the LNA is controlled by the AGC. The maximum gain is set with an external resistor, typically 26 dB with 1.5 kΩ.

2.4 AM - AGC

The programmable AM RFAGC senses the mixer inputs and controls the internal PIN diodes and LNA gains.

Firstly the LNA gain is reduced by about 10 dB, and then the PIN diodes are activated to further attenuate the signal.

The time constant of the 2nd order AM AGC LPF is defined by both external components and programmable internal currents.

2.5 AM - Mixers

The image rejection mixer has two AM inputs selectable via software. It easily supports low-cost applications for extended frequency bands like short-waves.

The input frequency is converted to low IF with high image rejection.

2.6 IF A/D converters

A high performance IQ-IFADC converts the IF signal to the digital domain for subsequent digital signal processing.

Two fully differential, continuous-time Sigma-Delta (ΣΔ) IF-ADCs are used for both the 'I' path and the 'Q' path. For each IFADC, two fully differential input nodes are fed with an input signal having a bandwidth up to 325 kHz. This fully differential design provides good suppression of even-order harmonics. For complex filtering, the input signals of the 'I' path and the 'Q' path have a 90 degree phase shift. The IFADC sampling frequency is 36.48 MHz.

2.7 Audio D/A converters

A CD-quality (>100dB DR) stereo DAC provides the left/right audio signals after IF processing and stereo-decoding by the DSP. In presence of an external HD Radio decoder the DAC delivers the high quality audio resulting from the decoding of the HD Radio transmissions. It can additionally be used to convert the signal digitally demodulated by an external DRM decoder to analog.

2.8 VCO

The VCO is fully integrated without any external tuning component. It covers all the FM frequency bands including EU, US, Japan, East-Europe, Weather-Band and the AM bands including LW, MW and SW. Its center frequency is approximately 2.7 GHz.

2.9 PLL

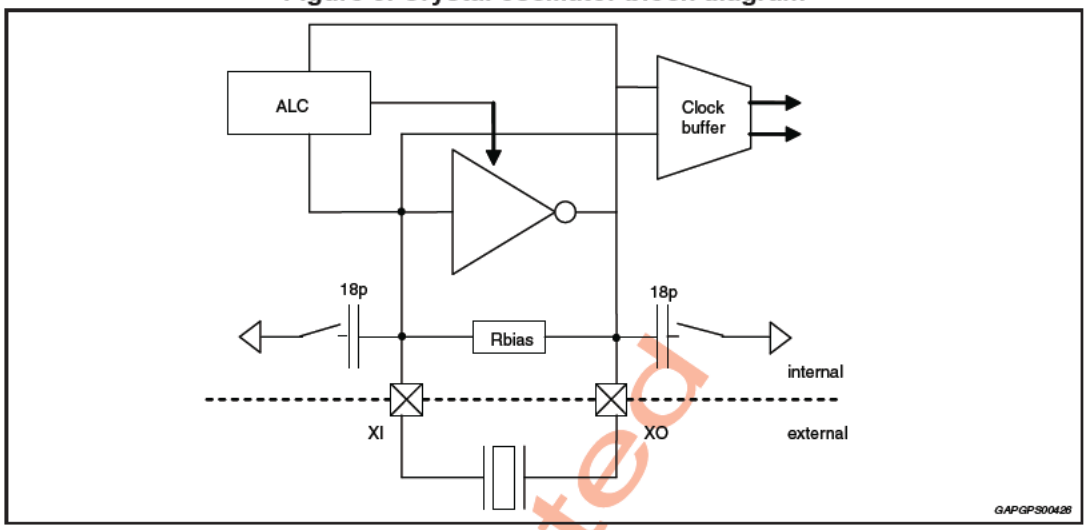
2.9.1 Tuner PLL

The very high-speed tuning PLL is able to settle within about 100 µs. The frequency step can be as low as 5 kHz in FM and 500 Hz in AM.

2.10 Crystal oscillator

The device works with a 36.48 MHz fundamental tone crystal. The oscillator block diagram is shown in *Figure 3*. On the PCB the crystal must be connected as close as possible to the chip oscillator input and output pins of the chip. The internal load capacitance together with pin and pad capacitance is optimized for fundamental tone crystal units at 36.48 MHz. It is not recommended to put any additional external load capacitors. By suitably configuring pin #9 (CK_SEL), the device can be operated as either a clock master or a clock slave. If pin 9 is left open or tied to GND, the device is configured as clock master (typical operation mode). In case the device is configured as clock slave, pin 9 needs to be connected to 5 V. Then the crystal oscillator is switched off and the device expects a crystal equivalent signal on the OSCout/OSCin pins.

Figure 3. Crystal oscillator block diagram



2.11 DSP and digital hardware accelerators

The TDA7786C embeds two DSP cores for high computational power and achievable customization. The DSP cores, in combination with the hardware accelerators, take care of all the tuner digital signal processing. The main program is fixed in ROM. Control parameters are copied to RAM and are accessible and modifiable there, thus allowing a parametric performance optimization. The operations performed by the DSP cores and HW accelerators are:

- digital down-conversion of IF
- bandwidth selection with variable controlled bandwidth
- FM and AM noise blanking
- FM/AM demodulation with soft-mute, high-cut, weak signal processing and quality detection
- FM stereo decoding with stereo-blend
- Self-alignment of pre-selection tuning

Table 3. I^2S interface timing (receiver)

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
t_{CLK}	Minimum Clock Cycle (CLK)	-	50	-	-	ns
t_{CLKH}	Minimum bit clock high time	-	25	-	-	ns
t_{CLKL}	Minimum bit clock low time	-	25	-	-	ns
t_{WSS}	Word-select setup time	slave mode	5	-	-	ns
t_{WSH}	Word-select hold time	slave mode	3	-	-	ns
t_{WSD}	Word-select delay	master mode	4	-	-	ns
t_{DS}	Data setup time	-	5	-	-	ns
t_{DH}	Data_hold time	-	5	-	-	ns

2.12 Serial control interface

The device is controlled via I^2C.

Through serial bus the processing parameters can be modified and the signal quality parameters can be read out.

The operation of the device is handled mainly through high level commands sent by the car-radio microprocessor through the serial interface, which allows simplification of the operations carried out in the microprocessor itself. The high level commands include among others:

- change frequency (which allows to avoid computing the PLL divider factors)
- change band;
- start seek (the seek operation can be carried out by the TDA7786C in a completely autonomous fashion).

2.12.1 Serial interface / boot mode

The device possesses two different I2C addresses: 0xC2/C3 and 0xC8/C9. The configuration is chosen by applying the proper voltage at the exit from reset to the pins indicated in *Table 4*. The configuration is latched (e.g. made effective) when the RSTN line transitions from low to high (when RSTN is low, the IC is in reset mode).

The voltage level forced to the boot pins must be released to start the system operation a suitable time after the RSTN line has gone high. The list of configurations is shown in the following table:

Table 4. Boot mode configuration

SAI_AUDIO_DO pin 39	ADDSEL pin 32	BUS mode
0	0	I^2C Address = 0xC2
0	1	I^2C Address = 0xC8

The status of these pins during the reset phase can be set to:

- High: through external <10 kΩ resistors tied to 3.3V
- Low: by not forcing any voltage on them from outside, as 50 kΩ internal pull-down resistors are present inside the device.

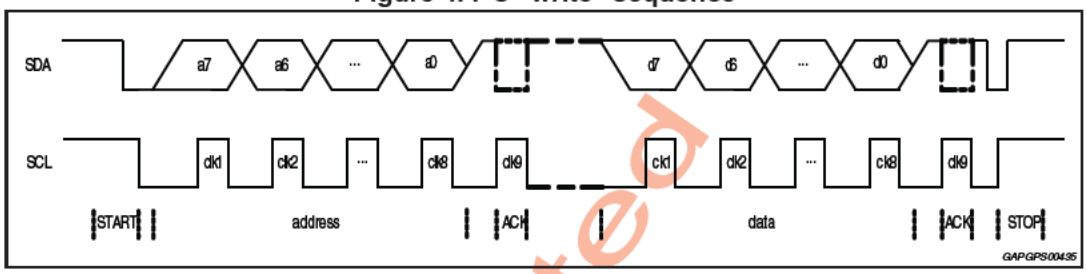
To make sure the I^2C address is correctly latched up at start-up, it is advisable to keep the RSTN line low until the IC supply pins have reached their steady state, and further keep it low for an additional time Treset.

2.12.2 I²C bus protocol

The I²C communication requires two signals: clock (SCL) and data (SDA - bidirectional). The protocol requires an acknowledge signal after any 8-bit transmission.

A "write" communication example is shown in the figure below, for an unspecified number of data bytes (see the relevant technical documentation for frame structure description):

Figure 4. I²C "write" sequence

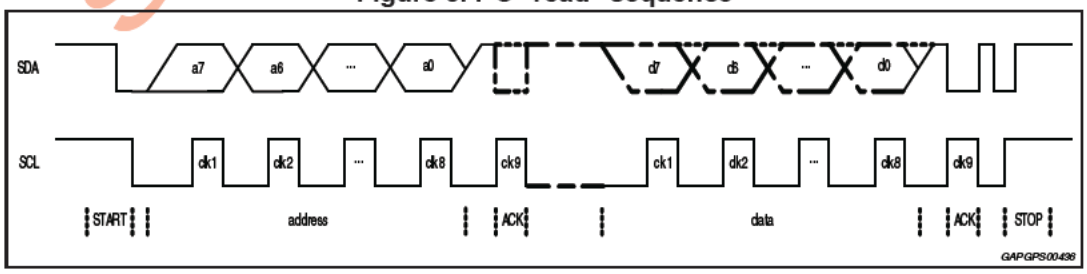


The sequence consists of the following phases:

1. START: SDA line transitioning from H to L with SCL fixed H. This indicates that a new transmission is starting;
2. DATA LATCHING: on the rising SCL edge. The SDA line can vary only when SCL is low (otherwise its transitions are interpreted as either a START or a STOP transition);
3. ACKNOWLEDGE: on the 9th SCL pulse the microprocessor keeps the SDA line H, and the TDA7786C pulls it down in case the communication has been successful. Lack of the acknowledge pulse generation from the TDA7786C indicates a communication failure; the chip-address byte must be sent at the beginning of the transmission. The value can be 0xC2 or 0xC8 (according to the mode chosen at start-up) for "write"; as many data bytes as needed can follow the address before the communication is terminated. See the next section for details on the frame format;
4. STOP: SDA line transitioning from L to H with SCL H. This signifies the end of the transmission.

Dashed lines represent transmissions from the TDA7786C to the microprocessor. A communication example is shown in the figure below, for an unspecified number of data bytes (see later on for frame structure description):

Figure 5. I²C "read" sequence



The "read" sequence is similar to the "write" and it has the same constraints for start, stop, data-latching and the following differences:

- the chip address must always be sent by the microprocessor to the TDA7786C; the address must be 0xC3 (if C2 has been selected at boot) or 0xC9 (if 0xC8 has been selected at boot);
- the header is transmitted after the chip address (the same happens for "write") before data are transferred from the TDA7786C to the microprocessor. See the relevant technical documentation for details on the frame format;
- when data are transmitted from the TDA7786C to the µP, the latter keeps the SDA line H;
- the acknowledge pulse is generated by the µP for those data bytes that are sent by the TDA7786C to the µP. Failure of the µP to generate an ACK pulse on the 9th CLK pulse has the same effect on the TDA7786C as a STOP.

The maximum clock speed is 500 kbit/s.

Warning: When the TDA7786C is not powered on, the internal ESD protection diodes act as a pull-down keeping the I^{2}C lines voltage below 2 V. This implies that the I^{2}C bus connected to the TDA7786C may not be used to drive other devices when the TDA7786C is powered off.

2.13 Digital-down-converter (DDC)

The complex digital mixer in the DDC performs mixing of the IF signal to zero IF. The internal sample rate for FM/AM processing is 456 kS/s.

Figure 6. Digital-down-converter simplified block diagram

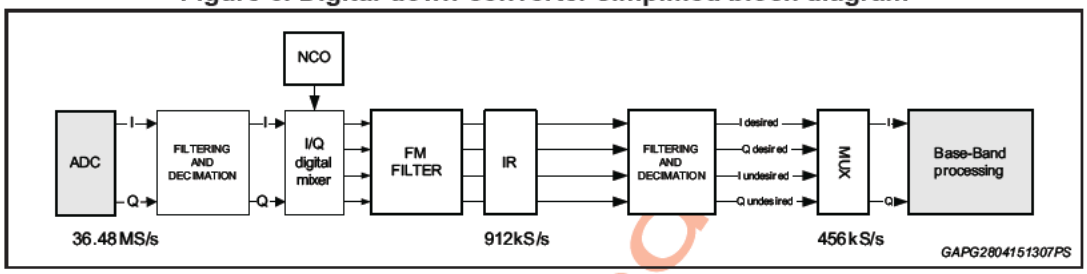


Figure 7. Cumulative digital-down-converter transfer function for FM

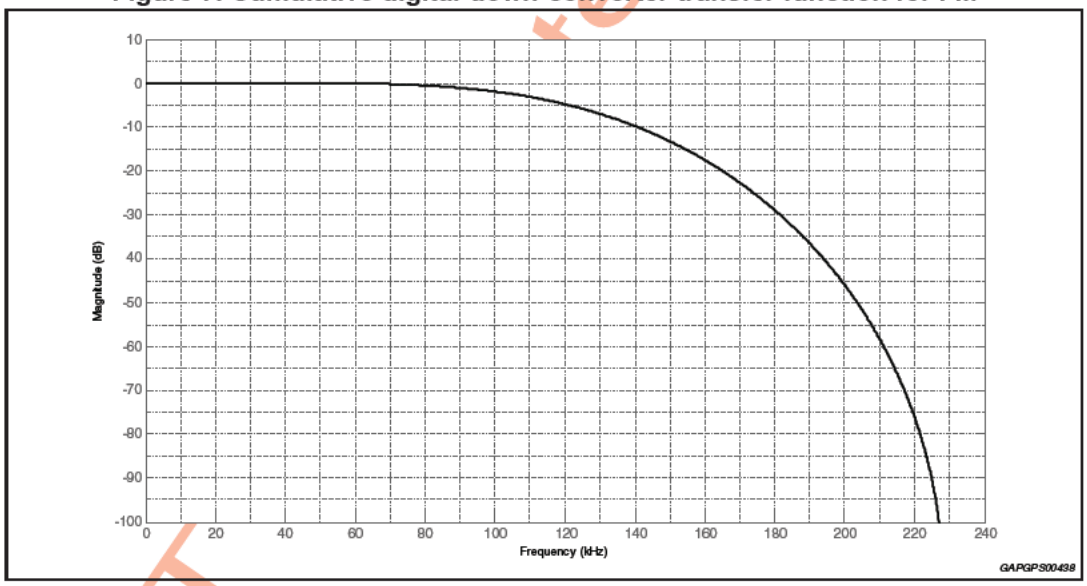


Table 5. Overall filter characteristics for FM (not including DISS filter)

Item	Value	Unit
Pass-band edge	45.8	kHz
Stop-band edge	228	kHz
In-band ripple	<0.003	dB
Anti-alias Attenuation	>100	dB

Figure 8. Cumulative digital-down-converter transfer function for AM

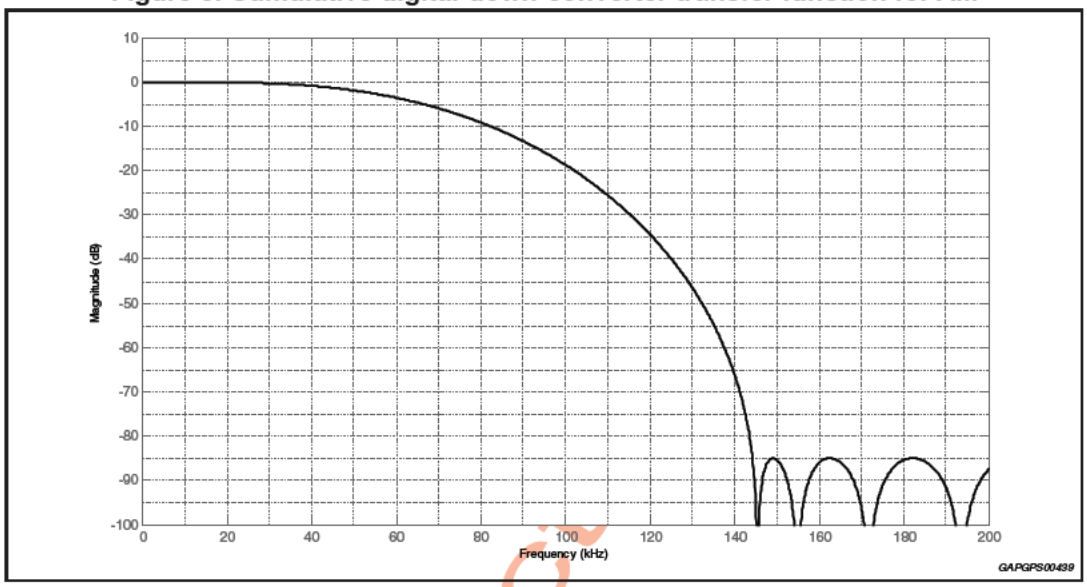


Table 6. Overall filter characteristics for AM

Item	Value	Unit
Pass-band edge	20	kHz
Stop-band edge	300	kHz
In-band ripple	<0.051	dB
Anti-alias Attenuation	>100	dB

3 Electrical specifications

3.1 Absolute maximum ratings

Table 7. Absolute maximum ratings

Symbol	Parameter	Test condition	Min	Typ	Max	Units
V_{CC}	Abs. supply voltage	-	-0.5	-	5.5	V
T_{stg}	Storage temperature	-	-55	-	150	°C
V_{ESD}	ESD absolute minimum withstand voltage	Human Body model	>|±2000|			V
		Charged device model	>|±400|			
		Charged device mode, corner pins	>|±750|			
-	Max. input at any pin (latch-up characteristic)	I_{INMAX}	±100			mA

Note: For all pins 37-44, when set as input, injecting current cannot exceed 20 mA as it would lead to voltage at the pin above the abs max.

3.2 Thermal data

Table 8. Thermal data

Symbol	Parameter	Test condition	Value	Units
R_{th}	Thermal resistance	LQFP64 10x10, JEDEC 2s1p PCB	55	°C/W

3.3 General key parameters

Table 9. General key parameters

Symbol	Parameter	Test condition	Min	Typ	Max	Units
V_{CC}	5 V supply voltage	see note (1)	4.7	5	5.2	V
I_{CC}	supply current @ 5 V		-	175	225	mA
T_{amb}	Ambient temperature range	-	-40	-	85	°C
$V_{VCCREG12}$	VCCREG12 supply voltage	see note (2)	2.3	-	5.2	V
V_{1V2}	Digital core 1.2 V supply voltage	when supplied externally see note (3)	1.14	1.2	1.3	V
I_{1V2}	Digital core 1.2 V supply current	V_{1V2} = 1.2V see note(3)	-	55	80	mA
V_{3V3}	Digital IO 3.3 V supply voltage	when supplied externally see note(4)	3.0	-	3.6	V

Table 9. General key parameters (continued)

Symbol	Parameter	Test condition	Min	Typ	Max	Units
I_{3V3}	Digital IO 3.3 V supply current	Maximum current specified only in case generated from Internal supply only	-	-	10	mA

1. FM functional test from antenna mixer input to audio output.
2. In the typical application supplied from 5 V with a 15 Ω series resistor.
   Test condition: maximum current load for minimum value, unloaded for maximum value.
3. When the 1.2 V supply is applied externally, and not using the internal 1.2 V regulator.
   Test condition: FM functional test from antenna mixer input to audio output.
4. When the 3.3 V supply is applied externally, and not using the internal 3.3 V regulator.

3.4 Electrical characteristics

V_{CC} = 4.7 V to 5.25 V; T_{amb} = -40 °C to +85 °C; unless otherwise specified.

3.4.1 FM - section

Table 10. FM - section

Symbol	Parameter	Test condition	Min	Typ	Max	Units
FM IMR Mixer						
RF Gain	Voltage gain (mix in -> s.e. test output)	RF gain 0	33	35	37	dB
		RF gain 1(1)	36	38	40	
		RF gain 2	37	39	41	
		RF gain 3	39	41	43	
Vnoise low gain	Input noise voltage (RF gain 0)	Rsource=1.25 kΩ, noiseless	-	2.3	2.9	nV/√Hz
		Rsource=0	-	2.1	2.6	
Vnoise high gain	Input noise voltage (RF gain 3)	Rsource=1.25 kΩ, noiseless	-	1.9	2.4	nV/√Hz
		Rsource=0	-	1.6	2.0	
IIP3	3rd order intercept point	RF gain 0, up to Vin/tone = 92 dBµV RF gain 3, up to Vin/tone = 86 dBµV	124 119	127 122	-	dBµV
FM AGC						
RFAGC-Thr	RFAGC threshold, referred to mixer input; RF level	min setting, reg8<14> =1	85.4	88.4	91.4	dBµV
		max setting, reg8<14>=1	89	92	95	
		min setting, reg8<14>=0	88.4	91.4	94.4	
		max setting, reg8<14>=0	92	95	98	
	Threshold steps	-	1.3	1.8	2.3	dB
	Threshold error	@ T_{amb}	-1.5	-	1.5	dB
	Threshold temperature drift	-	-	0.016	-	dB/K

Table 10. FM - section (continued)

Symbol	Parameter	Test condition	Min	Typ	Max	Units
IFAGC-Thr	IFAGC threshold	min setting	120	122	124	dBµV
		max setting	126	128	130	dBµV
	Threshold steps	-	1.5	2	2.5	dB
	Threshold error	@ T_{amb}	-1.5	-	1.5	dB
	Threshold temperature drift	-	-	0.016	-	dB/K
Time constant	I attack	Slow attack	10	20	30	µA
		Fast attack	100	200	300	
	I decay	Slow decay	1	2	5	
		Fast decay	10	20	30	
-	PIN diode source current	@ T_{amb} (2)	-15	-	-	mA
-	PIN diode sink current	-	3	-	20	µA
-	PIN diode source current in constant current mode	@ T_{amb}	-0.9	-	-	mA

1. The gain is internally 6 dB higher than what measured at the test output. This is due to the differential to single-ended conversion used for the test output.
2. The current is generated by a PTAT (proportional to absolute temperature) source, and has therefore a temperature dependency described by: ΔI/Io = ΔT/To, with Io being the current at ambient temperature (25 °C) and To the ambient temperature (25 °C) expressed in Kelvin, that is 298K.

3.4.2 AM - section

Table 11. AM - section

Symbol	Parameter	Test condition	Min	Typ	Max	Units
AM IMR Mixer						
Gain	Voltage gain (mix in -> s.e. test output)(1)	normal	20	22	24	dB
		reduced	17	19	21	
R_{in}	Input resistance	-	20	30	45	kΩ
V_{noise}	Input noise voltage	Mix 1, 2 R_{source} = 1 kΩ, noise-less	-	7.5	9	nV/√Hz
IIP3	3rd order intercept point	Mix1, 2 up to Vin/tone = 90 dBµV	128	132	-	dBµV
IIP2	2nd order intercept point	Mix1, 2 up to Vin/tone = 90 dBµV	152	158	-	dBµV
LO_{hsupp}	LO harmonic suppression	-	80	-	-	dB
AM LNA						
Gain	Voltage gain	Max gain, R_{ext} = 470 Ω	24	28	32	dB
		Min gain (AGC controlled)	8	12	16	
R_{in}	Input resistance	-	600	950	1300	kΩ
C_{in}	input capacitance	-	-	20	-	pF

Table 11. AM - section (continued)

Symbol	Parameter	Test condition	Min	Typ	Max	Units
V_{noise}	Input noise voltage	-	-	0.7	1.0	nV/√Hz
IIP3	3rd order intercept point	@ maximum LNA gain	116	120	-	dBµV
IIP2	2rd order intercept point	@ maximum LNA gain	121	127	-	dBµV
AM PIN diode						
IIP2	2rd order intercept point	Full attenuation, C_{source} = 80 pF, f = 1 MHz	134	140	-	dBµV
Res	Minimum resistance	-	-	5	15	Ω
C_{in}	Input capacitance	High ohmic	-	2	-	pF
AM AGC						
AGC-Thr	Referred to mixer input; RF level	Mix 1,2 min setting	80	83	86	dBµV
		Mix 1,2 max setting	92.6	95.6	98.6	
Thr-steps	Threshold steps	-	1.3	1.8	2.3	dB
-	Threshold error	@ T_{amb}	-2.5	-	2.5	dB
-	Threshold temperature drift	-	-3	-	3	dB
-	PIN diode source current	@ T_{amb} See note(2)	-10	-	-	mA
-	PIN diode sink current	-	15	30	45	µA
-	PIN diode source current in constant current mode	@ T_{amb} See note(2)	-1	-	-	mA

1. The gain is internally 6 dB higher than what measured at the test output. This is due to the differential to single-ended conversion used for the test output.
2. The current is generated by a PTAT (proportional to absolute temperature) source, and has therefore a temperature dependency described by: ΔI/Io = ΔT/To, with Io being the current at ambient temperature (25 °C) and To the ambient temperature (25 °C) expressed in Kelvin, that is 298K.

3.4.3 VCO

Table 12. VCO

Symbol	Parameter	Test condition	Min	Typ	Max	Units
$fvco_{,min}$	Minimum VCO oscillation frequency (1)	-	-	-	2.34	GHz
$fvco_{,max}$	Maximum VCO oscillation frequency (2)		3.025	-	-	GHz
PN	Phase noise of LO	Locked VCO; values referred @ 100MHz @ 100 Hz @ 1 kHz @ 10 kHz	-	 -105 -115 -115	-	dBc/Hz
dev	deviation error (RMS)	FM reception, deemphasis 50 µs, f_{audio}=20 Hz...20 kHz	-	5	8	Hz

1. Limited by application Firmware to 2.1 GHz.
2. Limited by application Firmware to 3.1 GHz.

3.4.4 Phase locked loop

Table 13. Phase locked loop

Symbol	Parameter	Test condition	Min	Typ	Max	Units
T_{settle}	Settling time FM	Δf < 10 kHz	-	100	140	µs
FM step	FM Frequency step	-	-	5	-	kHz
AM step	AM frequency step	-	-	500	-	Hz

3.4.5 Tuning DAC

Table 14. Tuning DAC

Symbol	Parameter	Test condition	Min	Typ	Max	Units
R_{es}	Resolution	8 bit	14	18	22	mV
V_{outmin}	Min output voltage	-	-	0.6	0.75	V
V_{outmax}	Max output voltage	-	VCC-0.25	VCC-0.15	-	V
R_{out}	Output impedance	-	1.5	2.5	3.5	kΩ
DNL	Diff. Nonlinearity	-	-	-	0.5	LSB
T_{conv}	Conversion time	Without capacitive load	-	20	-	µs

3.4.6 IF ADC

Table 15. IF ADC

Symbol	Parameter	Test condition	Min	Typ	Max	Units
DR_{FM}	Dynamic range in FM	BW = ±100 kHz	87	90	-	dB
$Vnoise_{FM}$	Input noise referred to mixer input	RF gain 2	1.7	0.94	-	nV/√Hz
DR_{AM}	Dynamic range in AM	BW = ±3 kHz	105	108	-	dB
$Vnoise_{AM}$	Input noise referred to mixer input	normal gain	6.3	3.2	-	nV/√Hz
DR_{FM-HD}	Dynamic range in FM-IBOC	BW = ±200 kHz	82	85	-	dB
$Vnoise_{FM-HD}$	Input noise referred to mixer input	RF gain 2	2.3	1.2	-	nV/√Hz
DR_{AM-HD}	Dynamic range in AM-IBOC	BW = ±15 kHz	97	100	-	dB
$Vnoise_{AM-HD}$	Input noise referred to mixer input	normal gain	5.6	2.9	-	nV/√Hz

3.4.7 Audio DAC

Table 16. Audio DAC

Symbol	Parameter	Test condition	Min	Typ	Max	Units
V_{out}	Max. output voltage	Full scale	1.2	1.4	-	Vrms
BW	Pass-band	0.01dB attenuation	-	20	-	KHz

Table 16. Audio DAC (continued)

Symbol	Parameter	Test condition	Min	Typ	Max	Units
Rout	Output resistance	-	100	150	200	Ω
multipath	Output noise	-	-	14	30	µVrms
D	Distortion	-6 dBFS	-	0.03	0.05	%

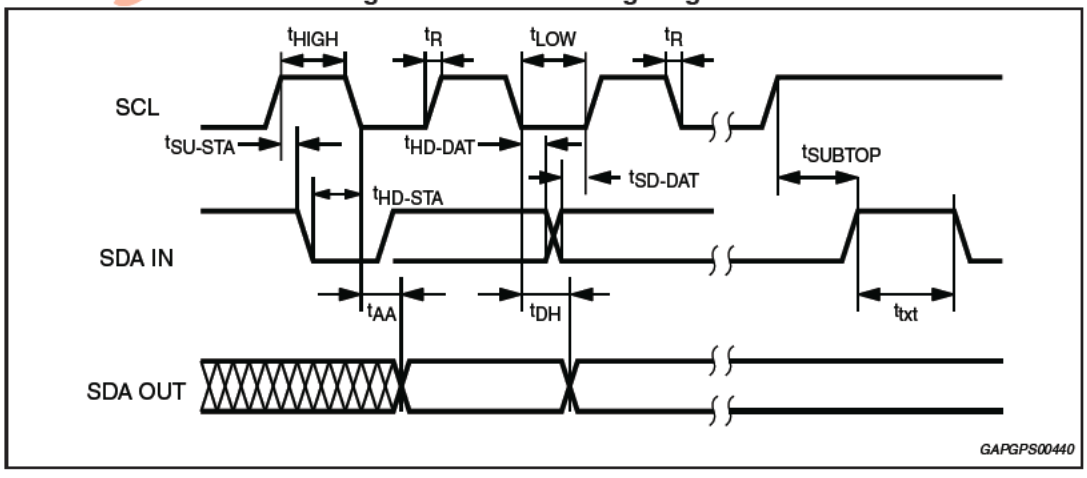
3.4.8 I²C interface

The I²C protocol serial bus communication parameters of the following table are defined as in *Figure 9*.

Table 17. I²C interface

Symbol	Parameter	Test condition	Min	Typ	Max	Units
f_{SCL}	SCL Clock frequency	-	-	-	500	kHz
t_{AA}	SCL low to SDA data valid	-	0.3	-	-	µs
t_{buf}	Time the bus must be kept free before a new transmission	-	1.3	-	-	µs
t_{HD-STA}	START condition hold time	-	0.6	-	-	µs
t_{LOW}	Clock low period	-	1.3	-	-	µs
t_{HIGH}	Clock high period	-	0.6	-	-	µs
t_{SU-SDA}	START condition setup time	-	0.1	-	-	µs
t_{HD-DAT}	Data input hold time	-	0	-	0.9	µs
t_{SU-DAT}	Data input setup time	-	0.1	-	-	µs
t_R	SDA & SCL rise time	-	-	-	0.3	µs
t_F	SDA & SCL full time	-	-	-	0.3	µs
$t_{SU-STOP}$	Stop condition setup time	-	0.6	-	-	µs
t_{DH}	Data out time	-	-	-	0.3	µs

Figure 9. I²C bus timing diagram

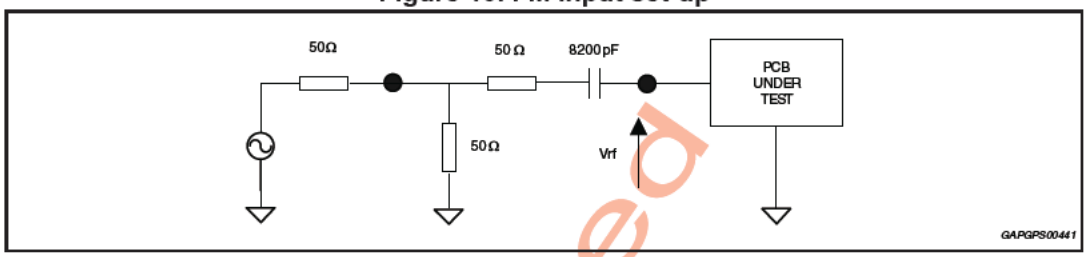


3.5 Overall system performance

3.5.1 FM overall system performance

Antenna level equivalence: 0 dBµV = 1 µVrms (Antenna terminal voltage with 75 Ω dummy load).

Figure 10. FM input set-up



Input level referred to 75 Ω antenna dummy output. F_{rf} = 98.1 MHz, V_{rf} = 60 dBµV, mono modulation, f_{dev} = 40 kHz, f_{audio} =1 kHz audio. De-emphasis = 50 µs. Wide-band, not-tuned pre-selection application, unless otherwise specified.

Table 18. FM overall system performance

Parameter	Test condition	Min	Typ	Max	Units
Tuning range FM Eu	(can be modified by the user) (automatic FE alignment available)	87.5	-	108	MHz
Tuning step FM Eu	(can be modified by the user)	-	100	-	kHz
Tuning range FM US	(can be modified by the user) (automatic FE alignment available)	87.5	-	107.9	MHz
Tuning step FM US	(can be modified by the user)	-	200	-	kHz
Tuning range FM Jp	(can be modified by the user) (automatic FE alignment available)	76	-	90	MHz
Tuning step FM Jp	(can be modified by the user)	-	100	-	kHz
Tuning range FM EEu	(can be modified by the user) (automatic FE alignment not available)	65	-	74	MHz
Tuning step FM EEu	(can be modified by the user)	-	100	-	kHz
Sensitivity	S/N = 26 dB	-	4	1	dBµV
S/N	@ 10 dBµV, no high-cut, DISS BW = #4	49	52	-	dB
Ultimate S/N	@ 60 dBµV, mono	77	80	-	dB
	@ 60 dBµV, Deviation = 75 kHz, mono	82	85	-	dB
	@ 60 dBµV, stereo	67	70	-	dB

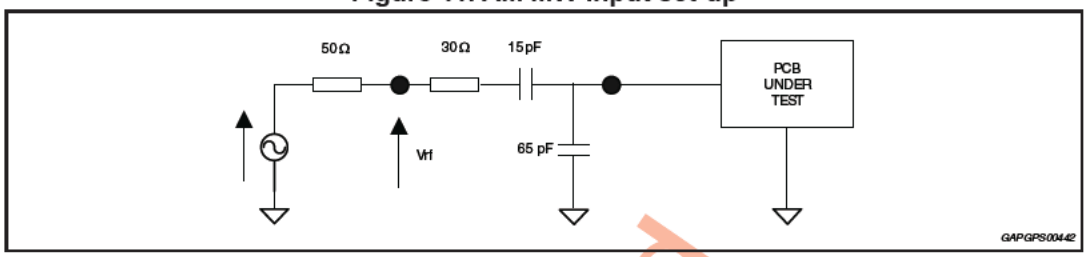
Table 18. FM overall system performance (continued)

Parameter	Test condition	Min	Typ	Max	Units
Distortion	Deviation= 75 kHz	-	0.05	0.1	%
Max deviation	THD=3%	150	166	-	kHz
Adjacent channel Selectivity (D/U ratio)	ΔF =100 kHz, SINAD=30 dB Desired 40 dBµV, dev = 40 kHz, 400 Hz undesired Dev=40 kHz, 1 kHz	20	30	-	dB
Alternate Channel Selectivity (D/U ratio)	ΔF = 200 kHz, SINAD=30 dB Desired 40 dBµV, dev = 40 kHz, 400 Hz undesired Dev=40 kHz, 1 kHz	52	62	-	dB
Max. Strong Signal Interferer (D/U ratio)	Desired = 40 dBµV SINAD = 30 dB Undesired ΔF = 1MHz	75	80	-	dB
3 signals performance ("wide-band") applications	Desired = 40 dBµV, dev = 40 kHz, 400 Hz, SINAD = 30 dB Undesired1 = ± 400 kHz, dev = 40 kHz, 1 kHz Undesired2 = ± 800 kHz, no mod	101	106	-	dBµV
	Desired = 40 dBµV, dev = 40 kHz, 400 Hz, SINAD = 30 dB Undesired1 = ±1 MHz, dev = 40 kHz, 1 kHz Undesired2 =±2MHz, no mod	105	110	-	dBµV
AM suppression	m = 30%	60	70	-	dB
Logarithmic field strength indicator	@40 dBµV read "FM_Smeter_log"	-0.41 (equivalent to 37 dBµV)	-0.38	-0.35 (equivalent to 43 dBµV)	-

3.5.2 AM MW overall system performance

Antenna level equivalence: 0 dBµV = 1 µVrms

Figure 11. AM MW input set-up



Level referred to SG EMF output before antenna dummy; dummy antenna load as shown above F_{rf} = 999 kHz (1000 kHz for US), V_{rf} =74 dBµV, mod = 30%, f_{audio} =400 Hz, unless otherwise specified.

Table 19. AM MW overall system performance

Parameter	Test condition	Min	Typ	Max	Units
Tuning range MW Eu/Jp	(can be modified by the user)	531	-	1629	kHz
Tuning step MW Eu/Jp	(can be modified by the user)	-	9	-	kHz
Tuning range MW US	(can be modified by the user)	530	-	1710	kHz
Tuning step MW US	(can be modified by the user)	-	10	-	kHz
Sensitivity	S/N = 20 dB	-	25	28	dBµV
Ultimate S/N	@ 80 dBµV	67	72	-	dB
AGC F.O.M.	Ref.=74 dBµV -10dB drop point	(1)	64	-	dB
Distortion	M=80%	-	0.1	0.2	%
Adjacent channel selectivity	ΔF = 9 kHz, SINAD = 26 dB undesired M = 30% 1 kHz	44	47	-	dB
Alternate channel selectivity	ΔF = 18 kHz, SINAD = 26 dB undesired M = 30% 1 kHz	48	51	-	dB
Strong signal interferer (1) SNR	ΔF = ±40 kHz desired = 40 dBµV undesired = 110 dBµV, m = 30% 1 kHz	8	12	-	dB
Strong signal interferer (1) suppression	ΔF = ±40 kHz desired = 40 dBµV undesired = 110 dBµV, m = 30% 1 kHz	-	10	15	dB
Strong signal interferer (1) cross-modulation	ΔF = ±40 kHz desired = 80 dBµV undesired = 110 dBµV, m = 30% 1 kHz maximum SNR of undesired channel	-	1	4	dB

Table 19. AM MW overall system performance (continued)

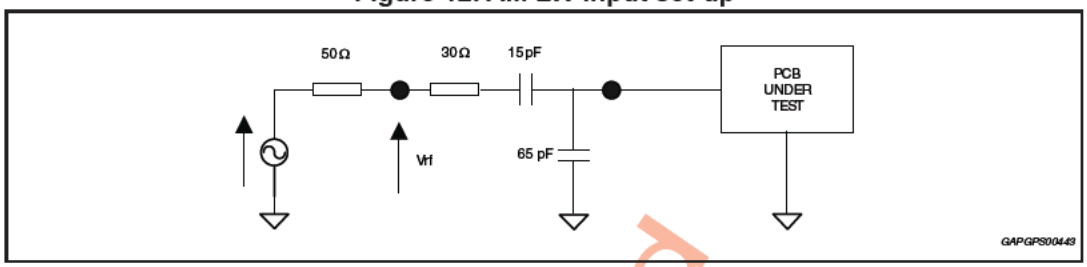
Parameter	Test condition	Min	Typ	Max	Units
Strong signal interferer (2) SNR	ΔF = ±400 kHz desired = 40 dBµV undesired = 110 dBµV, m = 30%, 1 kHz	5	11	-	dB
Strong signal interferer (2) suppression	ΔF = ±400 kHz desired = 40 dBµV undesired = 110 dBµV, m = 30%, 1 kHz	-	15	18	dB
Strong signal interferer (2) cross-modulation	ΔF = ±400 kHz desired = 80 dBµV undesired = 110 dBµV, m = 30%, 1 kHz maximum SNR of undesired channel	-	1	4	dB
Max. strong signal interferer	Desired = 40 dBµV SINAD = 26dB, blocking<6dB Undesired ΔF = 400 kHz, m = 30% (cross-mod. Test)	90	98	-	dBµV
Image rejection	-	60	80	-	dB
Logarithmic field strength indicator	@60 dBµV read "AM_SMeter_log"	-0.47 (equivalent to 57 dBµV	-0.44	-0.41 (equivalent to 63 dBµV)	-

1. Programmable by software parameters.

3.5.3 AM LW overall system performance

Antenna level equivalence: 0 dBµV = 1 µVrms

Figure 12. AM LW input set-up



Level referred to SG EMF output before antenna dummy; dummy antenna load as shown above F_{rf} =216 kHz, V_{rf} =74 dBµV, mod = 30%, f_{audio} = 400 Hz, unless otherwise specified.

Table 20. AM LW overall system performance

Parameter	Test condition	Min	Typ	Max	Units
Tuning range LW	(can be modified by the user)	144	-	288	kHz
Tuning step LW	(can be modified by the user)	-	1	-	kHz
Sensitivity	S/N = 20 dB	-	30	34	dBµV
Ultimate S/N	@ 80 dBµV	63	70	-	dB
AGC F.O.M.	Ref. = 74 dBµV -10dB drop point	(1)	64	-	dB
Distortion	M= 80%	-	0.1	0.2	%
Image rejection	-	60	80	-	dB

1. Programmable by software parameters.

4 Front-end registers

All the parameters in this section refer to the programmability of the FE part of the device (registers). The part of the registers that are not described here have either fixed values or values written by the tuner drivers, and are described in the proper technical documentation.

Table 21. Register 0x00

Register number																							Register definition
MSB																						LSB	
23	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	
																								AM mixer input selector
																						0	1	Input #1
																						1	0	Input #2
																								AM PIN diode
											0													Internal
											1													External
																								AM AGC mode
										0														LNA and PIN diode
										1														PIN diode only
																								AM AGC time constant
								0	0															Slow (125 ms with 1 µF)
								0	1															Medium (25ms with 1 µF)
								1	1															Fast (5ms with 1 µF)
																								AM AGC thresholds @ mixin
					0	0	0																	90.2 dBµV @ mixin
					0	0	1																	92.0 dBµV @ mixin
					0	1	0																	93.8 dBµV @ mixin
					0	1	1																	95.6 dBµV @ mixin
					1	0	0																	88.4 dBµV @ mixin
					1	0	1																	86.6 dBµV @ mixin
					1	1	0																	84.8 dBµV @ mixin
					1	1	1																	83 dBµV @ mixin
																								AM AGC attack time constant
			0																					Normal
			1																					Fast

Table 22. Register 0x01

Register number																						Register definition
MSB																					LSB	
23	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	
																								FM mixer RF-gain
																				0	0			35 dB
																				0	1			38 dB
																				1	0			39 dB
																				1	1			41 dB
																								FM mixer input
									0	1														Input #1 (single-ended)
									1	0														Input #2 (single-ended)
									1	1														Input #1/2 (differential)
																								FM AGC output mode
0	0																							Normal
0	1																							Constant 15mA
1	1																							Constant 1mA

Table 23. Register 0x02

Register Number																							Register Definition	
MSB																					LSB			
23	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	
																								FM RF AGC thresholds@ mixin
																						0	0	88.4 dBµV	Reg 0x008<14> = 1
																						0	1	90.2 dBµV	
																						1	0	92.0 dBµV	
																						1	1	93.8 dBµV	
																						0	0	91.4 dBµV	Reg 0x008<14> = 0
																						0	1	93.2 dBµV	
																						1	0	95.0 dBµV	
																						1	1	96.8 dBµV	
																								FM IFAGC threshold@IFADCin	
																				0	0			122 dBµV	
																				0	1			124 dBµV	
																				1	0			126 dBµV	
																				1	1			128 dBµV	
																								FMAGC attack time constant	
																			0					slow	
																			1					fast	
																								FMAGC decay time constant	
																		0						slow	
																		1						fast	
																								FM DAC	
																	0							off	
																	1							on	
																								FM DAC VALUE	
									0	0	0	0	0	0	0	0								0	
									0	0	0	0	0	0	0	1								1	
									…	…	…	…	…	…	…	…								…	
									1	1	1	1	1	1	1	1								255	

Table 24. Register 0x05

Register Number																						Register Definition
MSB																					LSB	
23	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	
																								GPODATA
																							0	low
																							1	high

Table 25. Register 0x08

Register number																						Register definition
MSB																					LSB	
23	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	
																								FMAGC gain select
									0															FM AGC thresholds high
									1															FM AGC thresholds down

5 Weak signal processing

All the parameters in this section refer to the programmability of the DSP part of the device. The typical values are those set by default parameters (start-up without parametric change from main microprocessor); the max and the min values refer to the programmability range. The values are referred to the typical application ('wide-band' in FM). Wherever the possible values are a discrete set, all the possible programmable values are displayed.

5.1 FM IF-processing

5.1.1 Dynamic channel selection filter (DISS)

Table 26. Dynamic channel selection filter (DISS) - discrete set

Symbol	Parameter	Test condition	Min	Typ	Max	Units
DISS BW	IF filter #10	response: - 3dB	-	±150	-	kHz
	IF filter #9		-	±120	-	kHz
	IF filter #8		-	±100	-	kHz
	IF filter #7		-	±85	-	kHz
	IF filter #6			±75	-	kHz
	IF filter #5			±65	-	kHz
	IF filter #4			±60	-	kHz
	IF filter #3			±55	-	kHz
	IF filter #2		-	±45	-	kHz
	IF filter #1		-	±35	-	kHz
	IF filter #0		-	±25	-	kHz

5.1.2 Soft mute

Table 27. Soft mute - continuous set

Symbol	Parameter	Test condition	Min	Typ	Max	Units
SMsp	Start point vs. field strength	audio atten = 1 dB read "FM_SoftMute" no adjacent channel present	0	6	20	dBµV
SMep	End point vs. field strength	audio atten = SMd + 1 dB read "FM_SoftMute" no adjacent channel present	-6	-6	10	dBµV
SMd	Depth		-30	-15	0	dB
SMtauatt	Field strength LPF cut-off frequency for soft mute activation		0.1	100	4000	Hz
SMtaurel	Field strength LPF cut-off frequency for soft mute release		0.1	1	4000	Hz

5.1.3 Adjacent channel mute

Table 28. Adjacent channel mute - continuous set

Symbol	Parameter	Test condition	Min	Typ	Max	Units
ACMd	Depth	-	SMd	0	0	dB

5.1.4 Stereo blend

Table 29. Stereo blend - continuous set

Symbol	Parameter	Test condition	Min	Typ	Max	Units
MaxSep	Maximum stereo separation	field strength = 80 dBµV, pilot deviation = 6.75 kHz	0	40	50	dB
SBFSsp	Start point vs. field strength	separation = MaxSep - 1 dB no multipath present	20	50	60	dBµV
SBFSep	End point vs. field strength	separation = 1 dB no multipath present	20	30	60	dBµV
SBFStM2S	Field strength-related transition time from mono to stereo	V_{rf} step-like variation from 20 dBµV to 80 dBµV	0.001	3	20	s
SBFStS2M	Field strength-related transition time from stereo to mono	V_{rf} step-like variation from 80 dBµV to 20 dBµV	0.001	0.5	20	s
SBMPsp	Start point vs. multipath	separation = MaxSep - 1 dB equivalent 19 kHz AM modulation depth; field strength = 80 dBµV	5	10	80	%
SBMPep	End point vs. multipath	separation = 1 dB equivalent 19 kHz AM modulation depth; field strength = 80 dBµV	5	30	80	%
SBMPtM2S	Multipath-related transition time from mono to stereo	V_{rf} step-like variation from 20 dBµV to 80 dBµV	0.001	1	20	s
SBMPtS2M	Multipath-related transition time from stereo to mono	V_{rf} step-like variation from 80 dBµV to 20 dBµV	0.001	0.001	20	s
Pil ThrM2S	Pilot detector stereo threshold	Threshold on pilot tone deviation for mono-stereo transition	0.8	2.74	-	kHz
Pil ThrHyst	Pilot detector threshold hysteresis	Difference in Pil. det. deviation threshold for stereo to mono transition compared to PilThrM2S	-	0.01	-	kHz

5.1.5 High cut control

Table 30. High cut control - continuous set

Symbol	Parameter	Test condition	Min	Typ	Max	Units
HCFSsp	Start point vs. field strength	minimum RF level for widest HC filter (filter # 7) no multipath present	0	50	50	dBµV
HCFSep	End point vs. field strength	maximum RF level for narrowest HC filter (filter # 0) no multipath present	0	30	40	dBµV
HCFStW2N	Field strength-related transition time from wide to narrow band	V_{rf} step-like variation from 60 dBµV to 10 dBµV	(1)			-
HCFStN2W	Field strength-related transition time from narrow to wide band	V_{rf} step-like variation from 0 dBµV to 60 dBµV	(1)	14	100	s
HCMPsp	Start point vs. multipath	minimum RF level for widest HC filter (filter # 7) equivalent 19 kHz AM modulation depth; field strength = 80 dBµV	5	10	150 (2)	%
HCMPep	End point vs. multipath	maximum RF level for narrowest HC filter (filter # 0) equivalent 19 kHz AM modulation depth; field strength = 80 dBµV	5	30	150 (2)	%
HCMPtN2W	Multipath-related transition time from narrow to wide band	V_{rf} step-like variation from 20 dBµV to 80 dBµV	0.001	0.001	20	s
HCMPtW2N	Multipath-related transition time from wide to narrow	V_{rf} step-like variation from 80 dBµV to 20 dBµV	0.001	0.001	20	s
HCmaxBW	Maximum cut-off frequency of high cut filter bank	Filter #7, -3 dB response frequency, input signal with pre-emphasis	HCmin BW	14	18	kHz
HCminBW	Minimum cut-off frequency of high cut filter bank	Filter #0, -3 dB response frequency, input signal with pre-emphasis	0.1	3	HCma xBW	kHz
HCnumFilt	Number of discrete HC filters	-	-	8 (3)	-	-

1. Depends only on field strength filter time constant.
2. Means that 100% equivalent 19 kHz AM modulation depth will not achieve full band narrowing.
3. Intermediate filters (#6 - #1) cut-off frequencies exponentially spaced between HCmaxBW and HCminBW.

Table 31. De-emphasis filter - continuous set

Symbol	Parameter	Test condition	Min	Typ	Max	Units
DEtc	De-emphasis time constant 1	-	-	50	-	µs
	De-emphasis time constant 2	-	-	75	-	

5.1.6 Stereo decoder

Table 32. Stereo decoder - continuous set

Symbol	Parameter	Test condition	Min	Typ	Max	Units
PilSup	Pilot signal suppression	Pilot 9%, 19 kHz, ref = 40 kHz	-	60	-	dB
SubcSup	Subcarrier suppression	f = 38 kHz	-	70	-	dB
		f = 57 kHz	-	70	-	dB
		f = 76 kHz	-	80	-	dB

5.2 AM IF-processing

5.2.1 Channel selection filter

Table 33. Channel selection filter

Symbol	Parameter	Test condition	Min	Typ	Max	Units
CSF BW	Channel selection filter BW	response: - 3dB	-	±3.7	-	kHz

5.2.2 Soft mute

Table 34. Soft mute - continuous set

Symbol	Parameter	Test condition	Min	Typ	Max	Units
SMsp	Start point vs. field strength	audio atten = 1 dB read “FM_SoftMute” no adjacent channel present	0	25	40	dBµV
SMep	End point vs. field strength	audio atten = SMd + 1 dB read “FM_SoftMute” no adjacent channel present	0	0	30	dBµV
SMd	Depth	-	-40	-24	0	dB
SMtauatt	Transition time for field strength-dependent soft mute activation	-	0.001	0.1	10	s
SMtaurel	Transition time for field strength-dependent soft mute release	-	0.001	3	10	s

5.2.3 High cut control

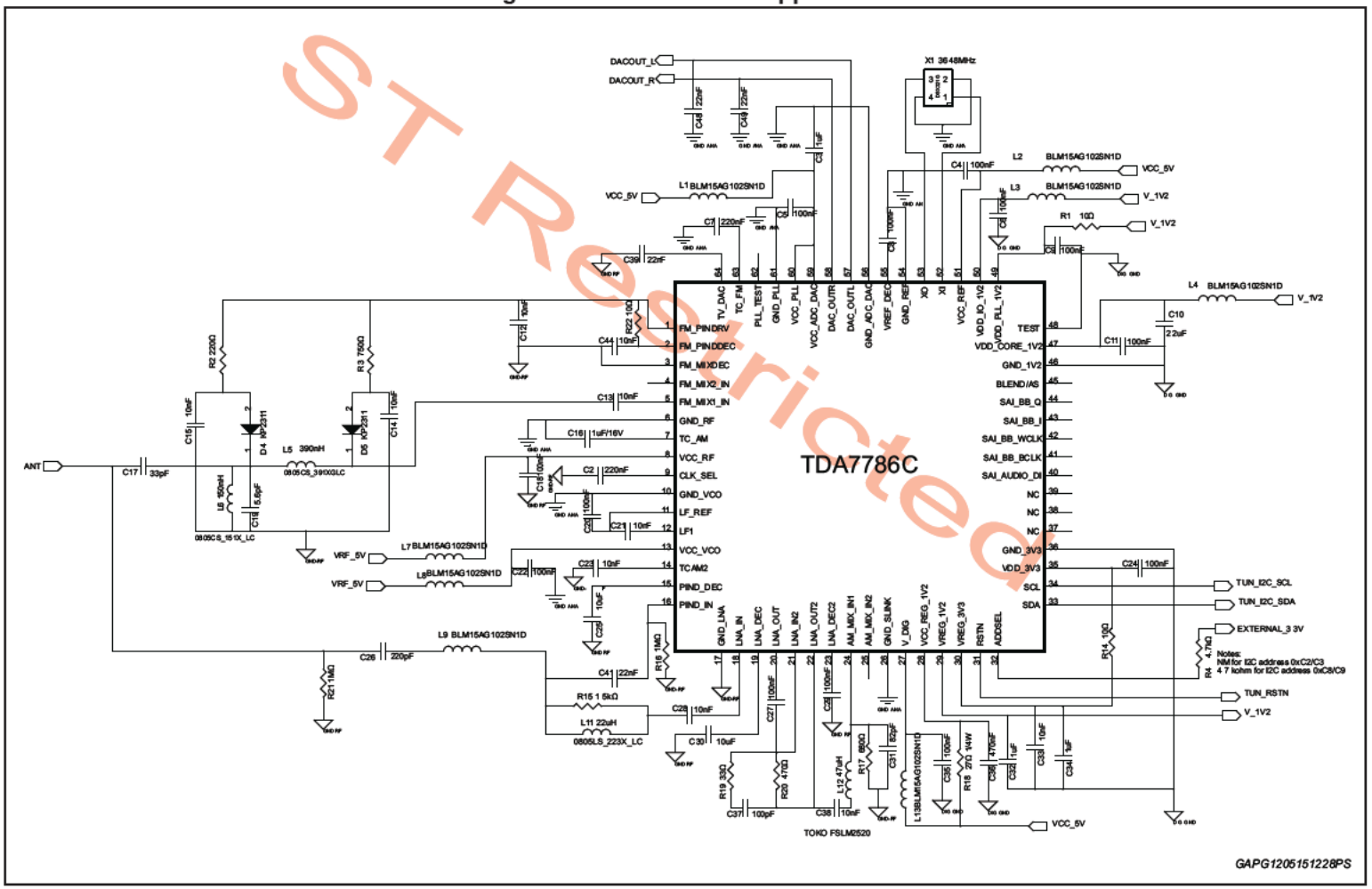
Table 35. High cut control - continuous set

Symbol	Parameter	Test condition	Min	Typ	Max	Units
HCFSsp	Start point vs. field strength	minimum RF level for widest HC filter (filter # 7) no multipath present	0	40	50	dBµV
HCFSep	End point vs. field strength	maximum RF level for narrowest HC filter (filter # 0) no multipath present	0	30	50	dBµV
HCFStW2N	Field strength-related transition time from wide to narrow band	V_{rf} step-like variation from 60 dBµV to 10 dBµV	0.001	0.2	20	s
HCFStN2W	Field strength-related transition time from narrow to wide band	V_{rf} step-like variation from 0 dBµV to 60 dBµV	0.001	10	20	s
HCmaxBW	Maximum cut-off frequency of high cut filter bank	Filter #7, -3 dB response frequency, input signal with pre-emphasis	HCminBW	14	18	kHz
HCminBW	Minimum cut-off frequency of high cut filter bank	Filter #0, -3 dB response frequency, input signal with pre-emphasis	1	3	HCmaxBW	kHz
HCnumFilt	Number of discrete HC filters	-	-	8	-	-

6 Application schematics

6.1 Basic application schematic

Figure 13. FM wide-band application



7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK® is an ST trademark.

7.1 LQFP64 (10x10x1.4 mm) package information

Figure 14. LQFP64 (10x10x1.4 mm) package outline

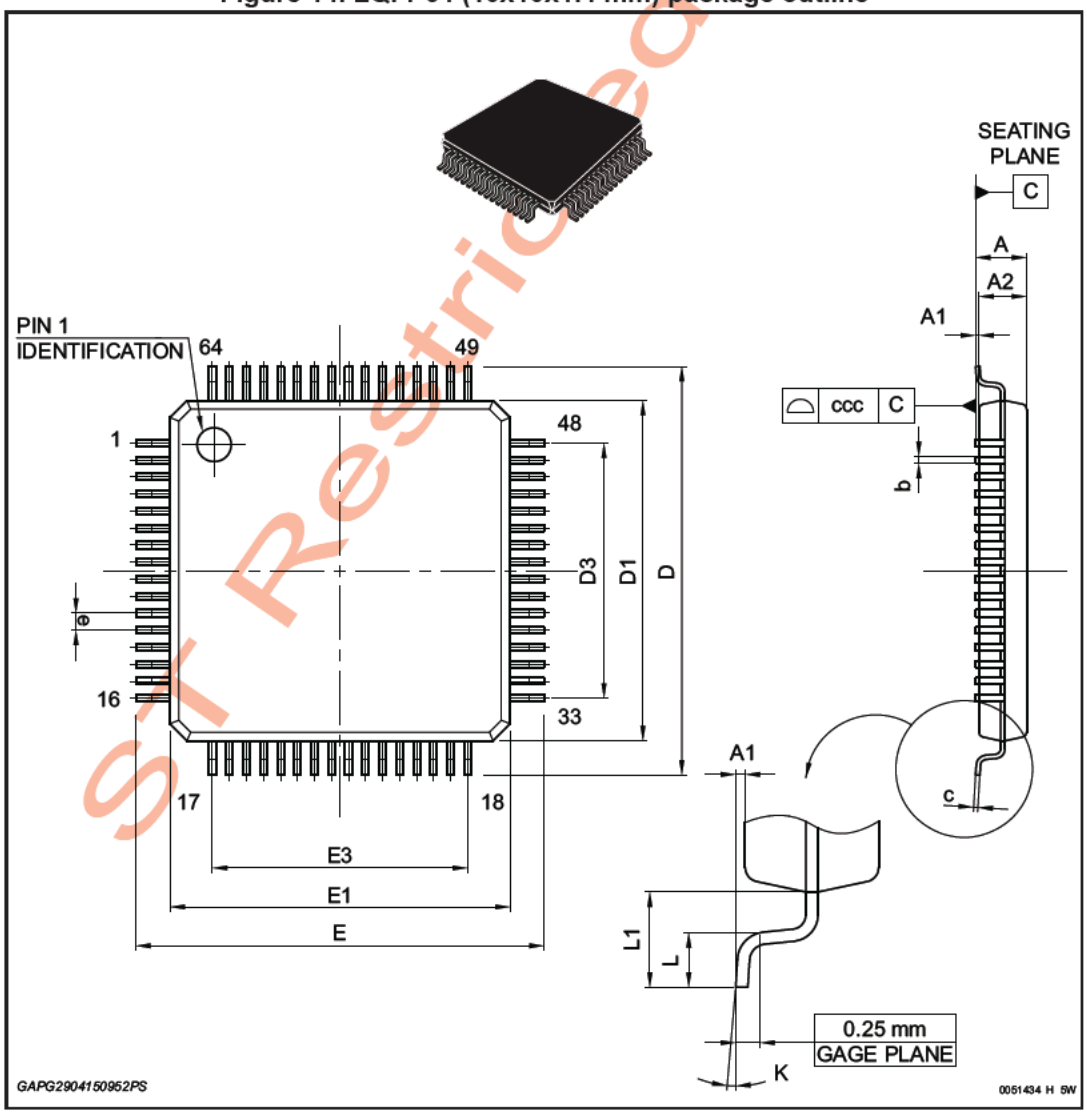


Table 36. LQFP64 (10x10x1.4 mm) package mechanical data

Ref	Dimensions					
	Millimeters			Inches[1]		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	-	-	1.60	-	-	0.0630
A1	0.05	-	0.15	0.0020	-	0.0059
A2	1.350	1.40	1.45	0.0531	0.0551	0.0571
b	0.17	0.22	0.27	0.0067	0.0087	0.0106
c	0.09	-	0.20	0.0035	-	0.0079
D	11.80	12.00	12.20	0.4646	0.4724	0.4803
D1	9.80	10.00	10.20	0.3858	0.3937	0.4016
D3	-	7.50	-	-	0.2953	-
E	11.80	12.00	12.20	0.4646	0.4724	0.4803
E1	9.80	10.00	10.20	0.3858	0.3937	0.4016
E3	-	7.50	-	-	0.2953	-
e	-	0.50	-	-	0.0197	-
L	0.45	0.60	0.75	0.0177	0.0236	0.0295
L1	-	1.00	-	-	0.0394	-
K	0	3.5	7	-	0.1378	0.2756
ccc	-	-	0.08	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

8 Revision history

Table 37. Document revision history

Date	Revision	Changes
18-May-2015	1	initial release.
08-Sep-2016	2	Updated in cover page: – Title; – Document status; – Description.